

same potential as a respective one of the first conductors and a respective one of the second conductors.

34. (Amended) A semiconductor device comprising:
a plurality of first conductors;
a first insulating film overlying the first conductors;

a plurality of thin film resistors overlying the first insulating film and electrically connected in series by the first conductors, each of the thin film resistors being made of a polysilicon film doped with B or BF₂ P-type impurities and overlying a respective one of the first conductors; and

first connecting means for electrically connecting each of the first conductors to an end of a respective one of the thin film resistors so that each of the first conductors is at the same potential as the respective one of the thin film resistors.

ADDITIONAL FEES:

No additional fees are believed required; however, should it be determined that a fee is due, authorization is hereby given to charge any such fee to our Deposit Account No. 01-0268.